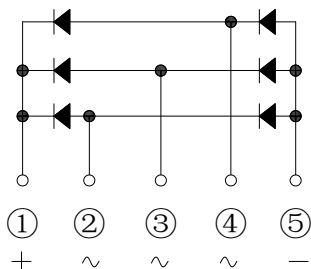
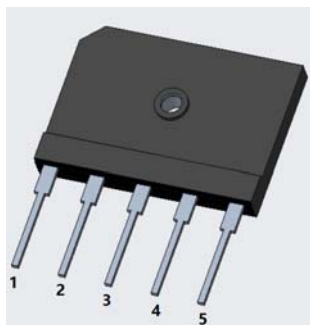


Three Phase Bridge Rectifiers



Features

- UL recognition, file #E230084
- Thin single in-line package
- Glass passivated chip junction
- High surge current capability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

General purpose use in AC/DC bridge full wave rectification for Server、Frequency converter、Industrial power supply.

Mechanical Data

- **Package:** 3GBJ
Molding compound meets UL 94 V-0 flammability rating, -
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked on body

■Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	DG15NA60	DG15NA80	DG15NA100	DG15NA120
Device marking code				DG15NA60	DG15NA80	DG15NA100	DG15NA120
Maximum Repetitive Peak Reverse Voltage		VRRM	V	600	800	1000	1200
Maximum RMS Voltage		VRMS	V	420	560	700	840
Maximum DC blocking Voltage		VDC	V	600	800	1000	1200
Average rectified output current @60Hz sine wave, R-load	With heatsink Tc =135°C	IO	A	15.0			
	Without heatsink Ta =25°C			4.0			
Forward Surge Current (Non-repetitive) @8.3ms Half-sine wave,1 cycle, Tj=25°C		IFSM	A	350			
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25°C				700			
Current squared time @1ms≤t≤8.3ms Tj=25°C, Rating of per diode		I²t	A²s	508			
Storage temperature		Tstg	°C	-55 ~ +150			
Junction temperature		Tj	°C	-55 ~ +150			
Dielectric strength @ Terminals to case, AC 1 minute		Vdis	KV	2.5			
Mounting torque @Recommend torque: 5kg·cm		Tor	kg·cm	8			

DG15NA60 THRU DG15NA120

■Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	DG15NA60	DG15NA80	DG15NA100	DG15NA120
Maximum instantaneous forward voltage drop per diode	V _F	V	I _{FM} =7.5A	1.0			
Maximum DC reverse current at rated DC blocking voltage per diode	I _R	μA	T _j =25°C	5			
			T _j =125°C	200			
Typical junction capacitance	C _j	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	140			

■Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	DG15NA60	DG15NA80	DG15NA100	DG15NA120
Typical Thermal Resistance	Between junction and ambient, Without heatsink	R _{θJ-A}	°C/W	18			
	Between junction and case, With heatsink	R _{θJ-C}		0.5			

Note: Device mounted on 75mm x 45mm x 5.5mm Aluminum Plate Heatsink.

■Ordering Information (Example)

PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
DG15NA60 ~ DG15NA120	A1	Approximate 10	100	100	1000	BOX
DG15NA60 ~ DG15NA120	B1	Approximate 10	10	/	1000	TUBE

■ Characteristics (Typical)

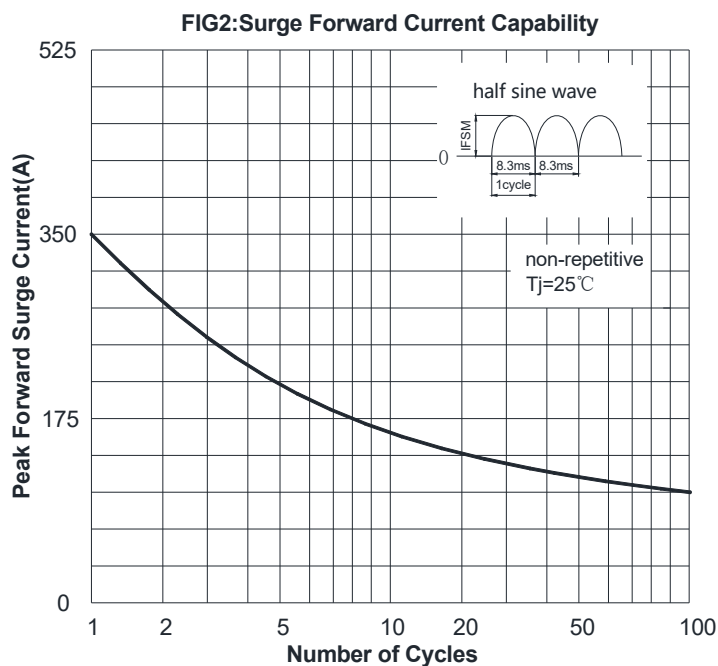
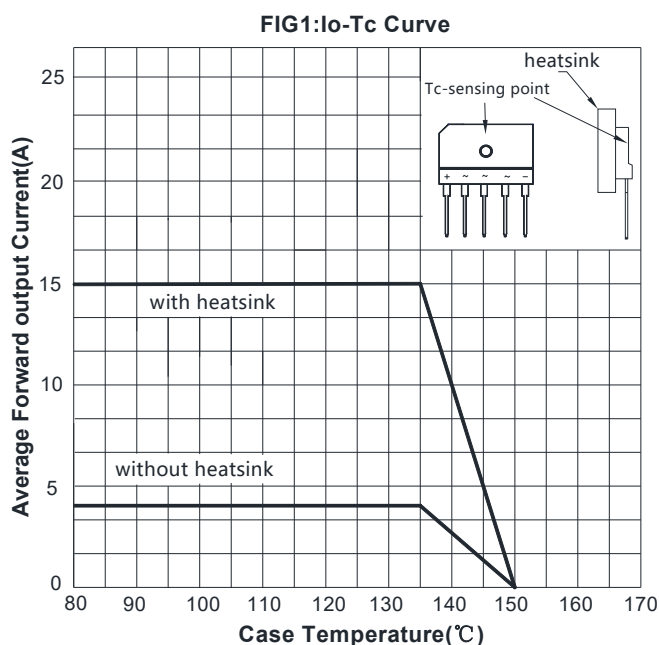


FIG3: Typical Forward Voltage

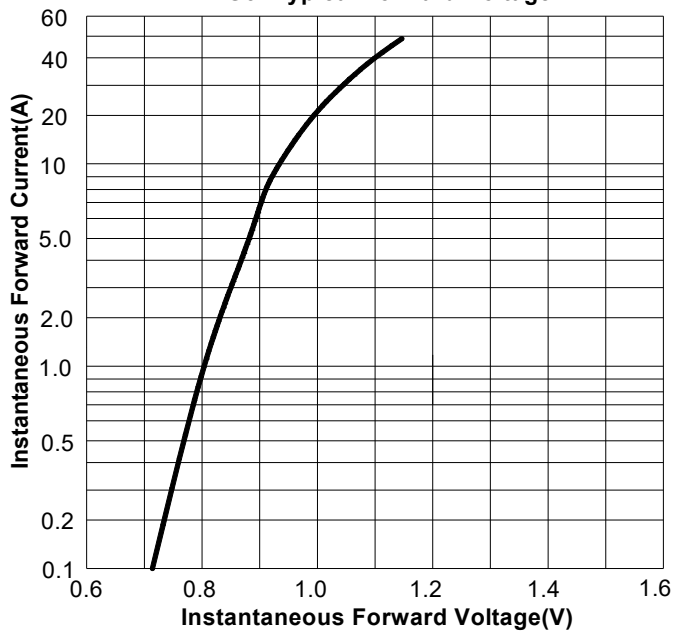
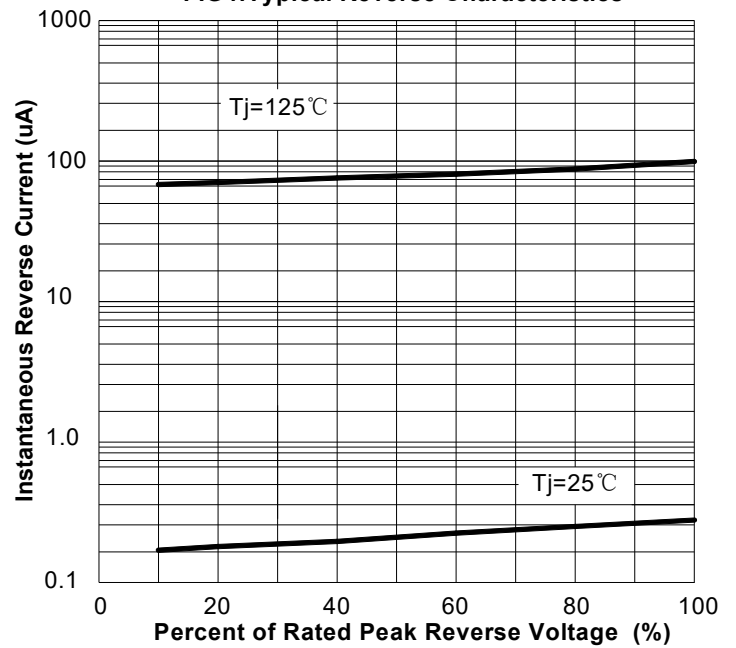
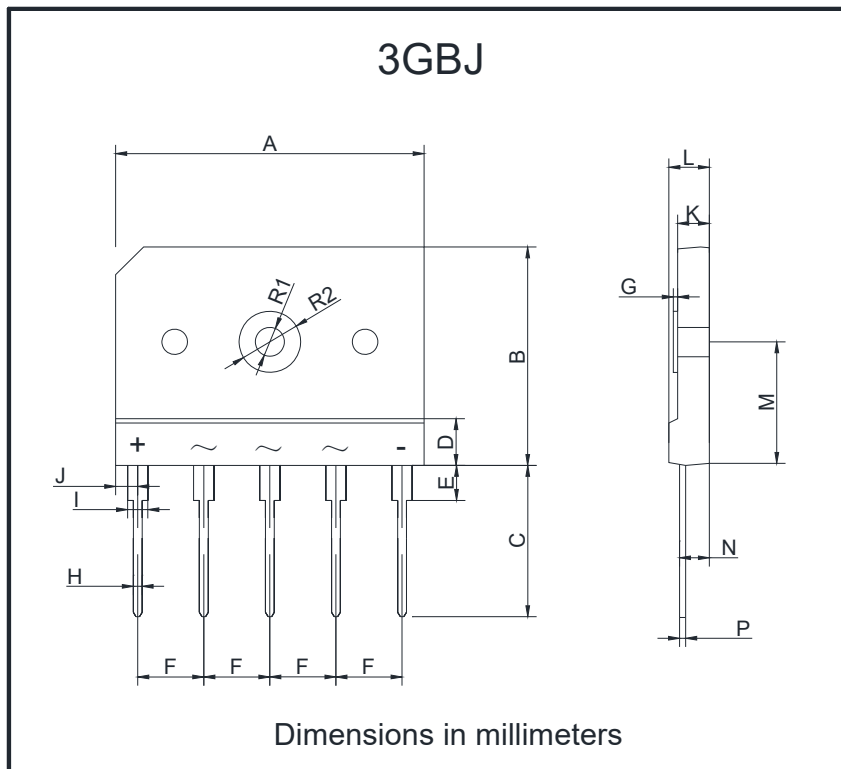


FIG4: Typical Reverse Characteristics



■ Outline Dimensions



3GBJ		
Dim	Min	Max
A	34.7	35.3
B	24.7	25.3
C	17.0	17.6
D	5.6	6.2
E	3.8	4.4
F	7.2	7.8
G	0.4	0.6
H	0.9	1.1
I	2.2	2.4
J	2.2	2.6
K	3.4	3.8
L	4.4	4.8
M	13.9	14.5
N	3.15	3.65
P	0.65	0.75
R1	2.7	3.7
R2	6.7	7.3

Disclaimer

The information presented in this document is for reference only. Shanghai Sunco Electronics Co., Ltd reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Russiansunco or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

This publication supersedes & replaces all information previously supplied. For additional information, please visit our website [http:// www.russiansunco.com](http://www.russiansunco.com) , or consult your nearest Russiansunco's sales office for further assistance.